MOSFETs Silicon N-channel MOS (U-MOSIV)

# TK20S06K3L

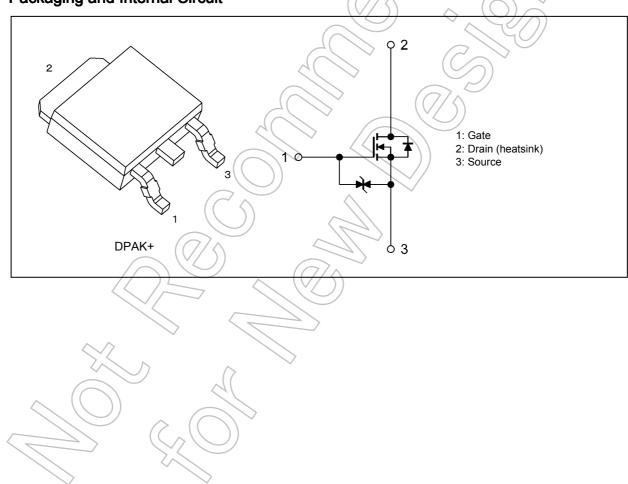
#### 1. Applications

- Automotive
- Motor Drivers
- DC-DC Converters
- Switching Voltage Regulators

#### 2. Features

- (1) AEC-Q101 qualified
- (2) Low drain-source on-resistance:  $R_{DS(ON)} = 23 \text{ m}\Omega$  (typ.) ( $V_{GS} = 10 \text{ V}$ )
- (3) Low leakage current:  $I_{\rm DSS}$  = 10  $\mu A$  (max) (V\_{\rm DS} = 60 V)
- (4) Enhancement mode:  $V_{th} = 2.0$  to 3.0 V ( $V_{DS} = 10$  V,  $I_D = 1$  mA)

#### 3. Packaging and Internal Circuit



### 4. Absolute Maximum Ratings (Note) ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristi	cs		Symbol	Rating	Unit
Drain-source voltage			V <sub>DSS</sub>	60	V
Gate-source voltage			V <sub>GSS</sub>	±20	
Drain current (DC)		(Note 1)	I <sub>D</sub>	20	A
Drain current (pulsed)		(Note 1)	I <sub>DP</sub>	40	
Power dissipation	(T <sub>c</sub> = 25°C)		PD	38	W
Single-pulse avalanche energy		(Note 2)	E <sub>AS</sub>	17	mJ
Avalanche current			I <sub>AR</sub>	20	A
Channel temperature		(Note 3)	T <sub>ch</sub>	) 175	°C
Storage temperature		(Note 3)	T <sub>stg</sub>	-55 to 175	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### 5. Thermal Characteristics

(	Characteristics		Symbol	Max	Unit
Channel-to-case thermal resistance	$\angle \langle \rangle$	$(\vee / )$	R <sub>th(ch-c)</sub>	3.9	°C/W
		$\overline{\langle \cdot \rangle}$	/		

Note 1: Ensure that the channel temperature does not exceed 175°C.

Note 2:  $V_{DD}$  = 25 V,  $T_{ch}$  = 25°C (initial), L = 58  $\mu$ H,  $R_G$  = 1  $\Omega$ ,  $I_{AR}$  = 20 A

Note 3: The definitions of the absolute maximum channel and storage temperatures are qualified per AEC-Q101.

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

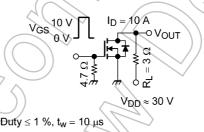
#### 6. Electrical Characteristics

### 6.1. Static Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I <sub>GSS</sub>	$V_{GS}$ = ±16 V, $V_{DS}$ = 0 V	_	_	±10	μA
Drain cut-off current	I <sub>DSS</sub>	V <sub>DS</sub> = 60 V, V <sub>GS</sub> = 0 V	Z	_	10	
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	60		_	V
	V <sub>(BR)DSX</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = -20 V	40	$\langle \gamma \rangle$	_	
Gate threshold voltage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	2.0	2_	3.0	
Drain-source on-resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> = 6 V, I <sub>D</sub> = 10 A	$/ \uparrow$	26	40	mΩ
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 10 A	$\sum$	23	29	

### 6.2. Dynamic Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	- /	780	Ι	pF
Reverse transfer capacitance	C <sub>rss</sub>		((	75		
Output capacitance	C <sub>oss</sub>			136	) —	
Switching time (rise time)	tr	See Figure 6.2.1.	$\sim$	8	—	ns
Switching time (turn-on time)	t <sub>on</sub>			16	—	
Switching time (fall time)	t <sub>f</sub>			6	_	
Switching time (turn-off time)	t <sub>off</sub>			24	_	





## 6.3. Gate Charge Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx 48 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	—	18	_	nC
Gate-source charge	Q <sub>gs</sub>		_	12	_	
Gate-drain charge	Q <sub>gd</sub>		_	6	_	

## 6.4. Source-Drain Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	$\square$	Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (DC)	(Note 4)	I <sub>DR</sub>	—	_	_	20	А
Reverse drain current (pulsed)	(Note 4)	I <sub>DRP</sub>	—	_	_	40	
Diode forward voltage		V <sub>DSF</sub>	I <sub>DR</sub> = 20 A, V <sub>GS</sub> = 0 V	_	_	-1.2	V
Reverse recovery time		t <sub>rr</sub>	I <sub>DR</sub> = 20 A, V <sub>GS</sub> = 0 V		36		ns
Reverse recovery charge		Q <sub>rr</sub>	-dI <sub>DR</sub> /dt = 50 A/μs	_	22	_	nC

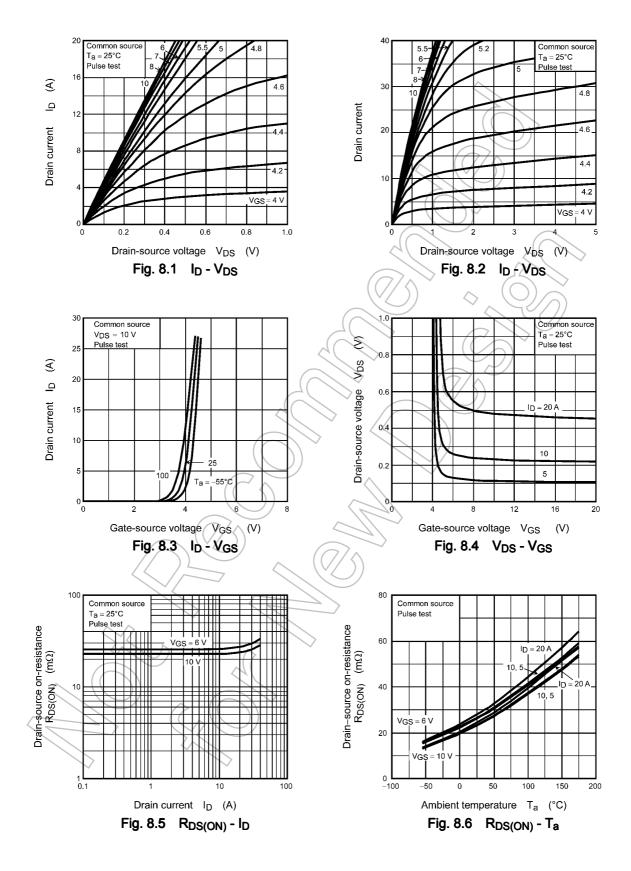
Note 4: Ensure that the channel temperature does not exceed 175°C.

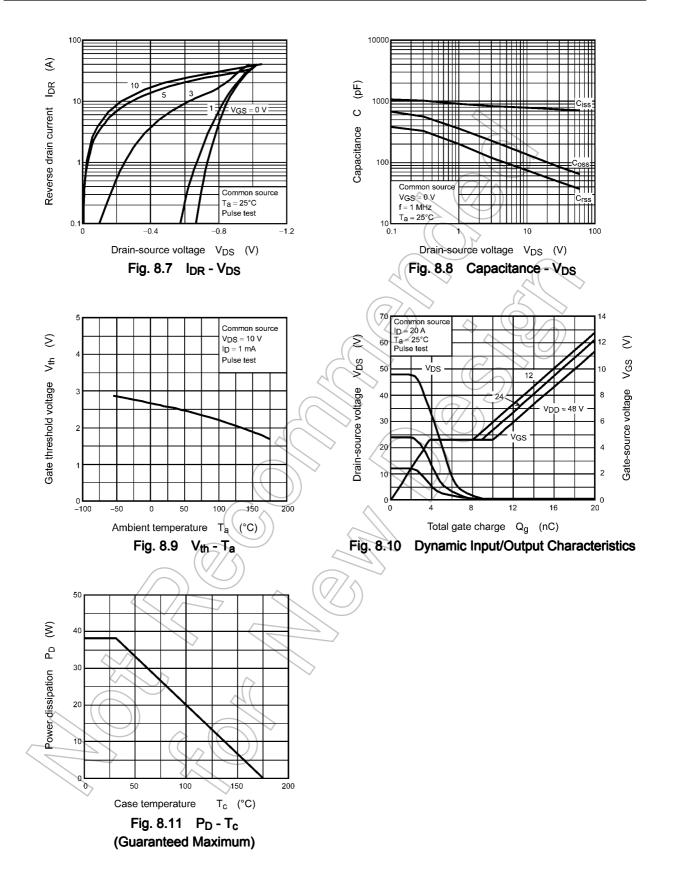
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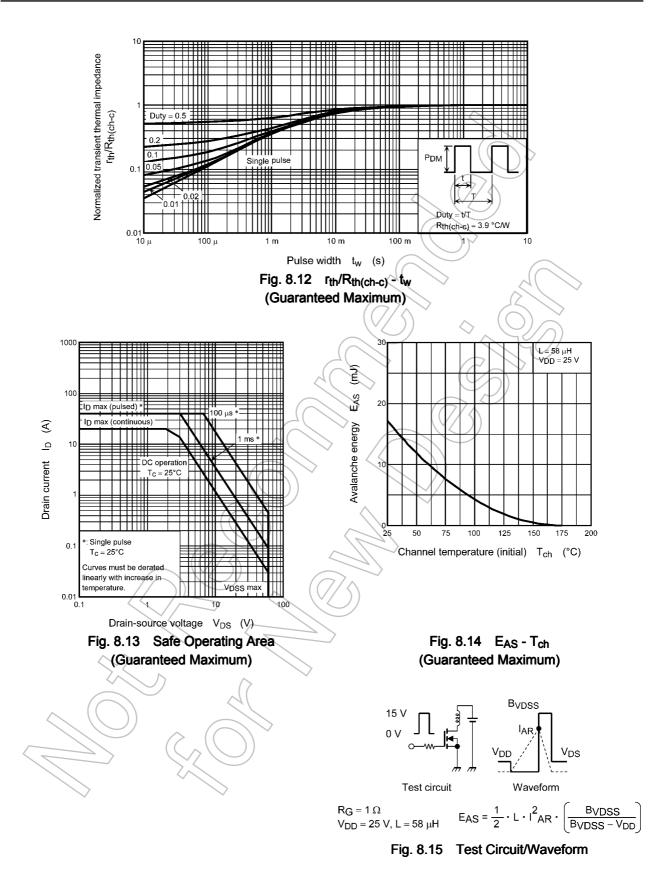
## TOSHIBA 7. Marking (Note)

	K20S06K3 ← Part No. (or abbreviation code) L Lot No. Note
	Fig. 7.1 Marking
Note:	A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]] Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

### 8. Characteristics Curves (Note)







Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

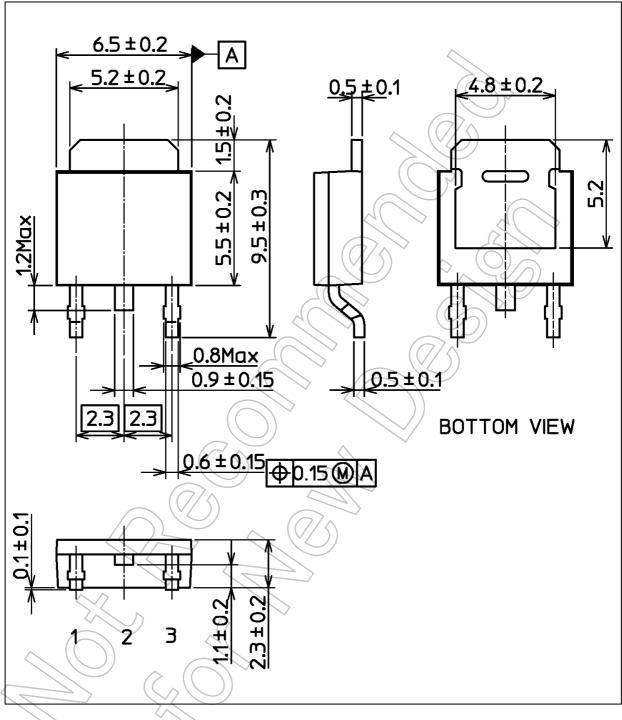
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### **Package Dimensions**

TK20S06K3L

Unit: mm



Weight: 0.36 g (typ.)

	Package Name(s)	
TOSHIBA: 2-7M1A		
Nickname: DPAK+		

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